

Docket No.: 8733.713.10
(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:
Han-Wook HWANG

Confirmation No.: TBA

Application No.: TBA

Group Art Unit: TBA

Filed: TBA

Examiner: TBA

For: POLY-CRYSTALLINE THIN FILM
TRANSISTOR AND FABRICATION
METHOD THEREOF

Customer No.: 30827

FIRST PRELIMINARY AMENDMENT

MS Patent Application
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

INTRODUCTORY COMMENTS

Prior to examination on the merits, please amend the above-identified U.S. patent application as follows:

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Claims are reflected in the listing of claims, which begins on page 3 of this paper.

Remarks begin on page 6 of this paper.